

Longitudinal Conductivity in Si/SiGe Heterostructure at Integer Filling Factors

Thursday, 4 September 2003 09:40 (0:20)

Content

Summary

Primary author(s) : I. SHLIMAK (Bar-Ilan University, Ramat Gan, Israel)

Presenter(s) : I. SHLIMAK (Bar-Ilan University, Ramat Gan, Israel)

Session Classification : Longitudinal Conductivity in Si/SiGe Heterostructure at Integer Filling Factors